High Performance Schottky Rectifier, 100 A

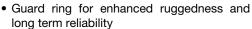


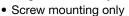
PowerTab®

PRODUCT SUMMARY			
Package	PowerTab [®]		
I _{F(AV)}	100 A		
V_{R}	15 V		
V _F at I _F	0.45 V		
I _{RM}	870 mA at 100 °C		
T _J max.	125 °C		
Diode variation	Single die		
E _{AS}	9 mJ		

FEATURES

- Ultralow forward voltage drop
- Optimized for OR-ing applications





 Designed and qualified according to JEDEC®-JESD47





- 125 °C max. operating junction temperature (V_R < 5 V)
- High frequency operation
- Continuous high current operation
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-100BGQ015 Schottky rectifier has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
1	Rectangular waveform	100	A		
I _{F(AV)}	T _C	88	°C		
V _{RRM}		15	V		
I _{FSM}	t _p = 5 μs sine	5000	А		
V	100 A _{pk} (typical)	0.39	V		
V _F	TJ	125	°C		
T _J	Range	-55 to +125	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-100BGQ015	UNITS
Maximum DC reverse voltage V _R	V	T _J = 100 °C	15	V
	T _J = 125 °C	5	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 88 °C, rectangular waveform		100	Α
Maximum peak one cycle	-	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	5000	Α
non-repetitive surge current	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	1000	^
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 4.5 \text{mH}$		9	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 3 x V _R typical		Α	



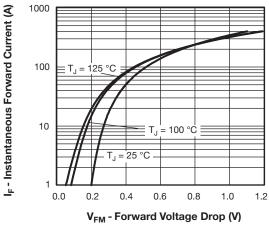
ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
For and allowed as	V _{FM} ⁽¹⁾	50 A	T _J = 25 °C	0.36	0.4	V
		100 A		0.45	0.52	
Forward voltage drop		50 A	T _J = 125 °C	0.27	0.31	
		100 A		0.39	0.45	
Marin and a second a second and		T _J = 100 °C, V _R = 12 V		480	700	mA
	I _{RM} ⁽¹⁾	$T_J = 125 ^{\circ}\text{C}, V_R = 5 ^{\circ}\text{V}$		1	1.2	Α
Maximum reverse leakage current		T _J = 25 °C	V _R = Rated V _R	7	18	A
		T _J = 100 °C		580	870	mA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz), 25 °C		38	00	pF
Typical series inductance	L _S	Measured from tab to mounting plane		3.	.5	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10	000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		-55 to +125	°C	
Maximum storage temperature range	T _{Stg}		-55 to +150		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.50	°C/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.30	C/VV	
Approximate weight			5	g	
Approximate weight			0.18	oz.	
Mounting torque			1.2 (10)	N·m	
Mounting torque maximum			2.4 (20)	(lbf \cdot in)	
Marking device		Case style PowerTab®	100B0	Q015	





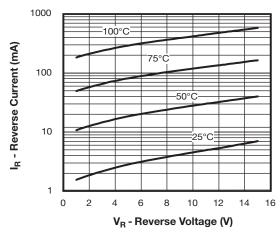


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

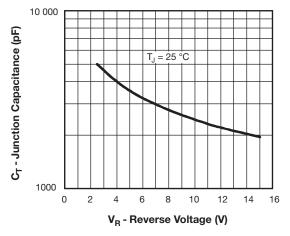


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

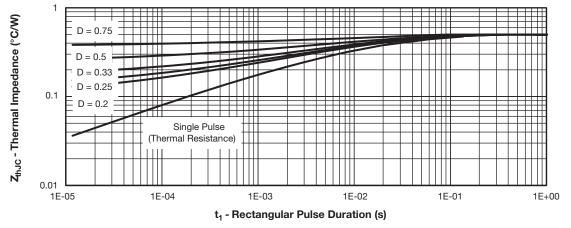
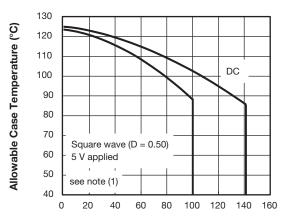


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



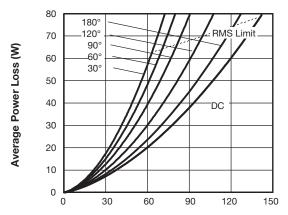
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I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



I_{F(AV)} - Average Forward Current (A)

Fig. 6 - Forward Power Loss Characteristics

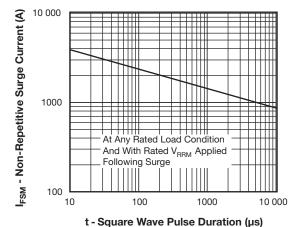


Fig. 7 - Maximum Non-Repetitive Surge Current

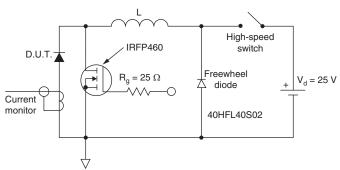


Fig. 8 - Unclamped Inductive Test Circuit

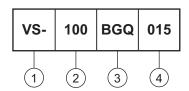
Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_{R} (1 - D); I_{R} \text{ at } V_{R1} = 5 \text{ V}$



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating

Essential part number

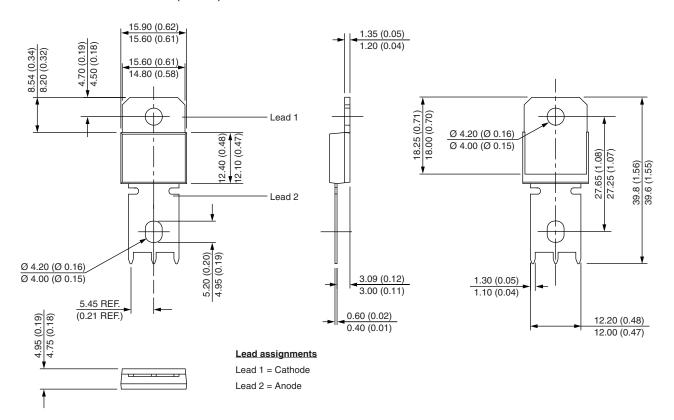
Voltage code = V_{RRM}

LINKS TO RELATED DOCUMENTS			
Dimensions www.vishay.com/doc?95240			
Part marking information	www.vishay.com/doc?95370		
SPICE model	www.vishay.com/doc?95428		
Application note	www.vishay.com/doc?95179		



PowerTab[®]

DIMENSIONS in millimeters (inches)





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